Data Sheet

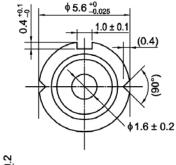
HL6366DG/67DG

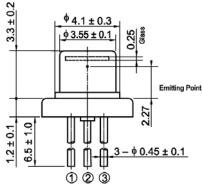
642nm/90mW

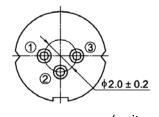
AlGaInP Laser Diode

USHIO

Outline



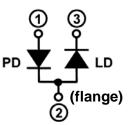




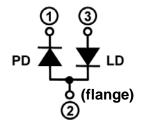
(unit:mm)

Internal Circuit





·HL6367DG



Features

- Visible light output: 642nm Typ.
- Optical output power: 80mW (CW)
- Single transverse mode
- Low operating current: 155mA Typ.
- Low operating voltage: 2.7V Max.
- Operating temperature: +50°C
- TE mode oscillation

Application

- Laser module
- Light source of optical equipments



Absolute Maximum Ratings (Tc=25°C)

| Item | Symbol | Ratings | Unit |
|-----------------------|--------------------|-----------|------|
| Optical output power | Ро | 90 | mW |
| LD Reverse Voltage | V _{R(LD)} | 2 | V |
| PD Reverse Voltage | V _{R(PD)} | 30 | V |
| Operating Temperature | Topr | -10 ~ +50 | °C |
| Storage Temperature | Tstg | -40 ~ +85 | °C |

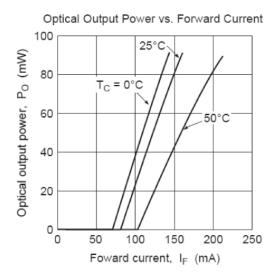
Optical and Electrical Characteristics (Tc=25°C)

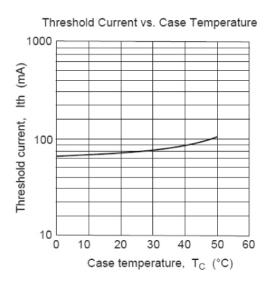
| Parameter | Symbol | Min | Тур | Max | Unit | Test Condition |
|--|--------|-----|-----|-----|------|-----------------------|
| Threshold current | Ith | - | 80 | 95 | mA | - |
| Operating current | lop | - | 155 | 175 | mA | Po=80mW |
| Operating voltage | Vop | - | 2.5 | 2.7 | V | Po=80mW |
| Beam divergence Parallel to the junction | θ// | 7 | 10 | 13 | 0 | Po=80mW, FWHM |
| Beam divergence Perpendicular to the junction | θΤ | 16 | 21 | 24 | 0 | Po=80mW, FWHM |
| Lasing Wavelength | λр | 635 | 642 | 645 | nm | Po=80mW |
| Monitor Current | Is | 0.1 | 0.3 | 0.5 | mA | Po=80mW, VR(PD)=5V |

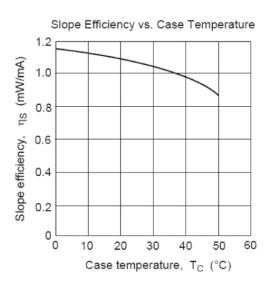
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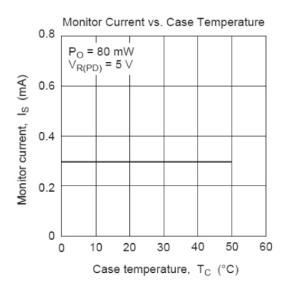


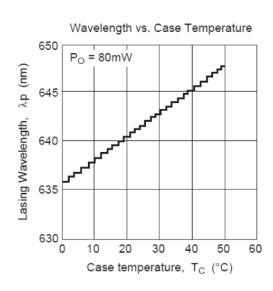
Typical Characteristic Curves

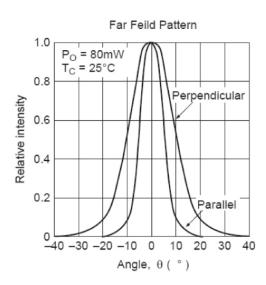












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